

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Jong-Lam LEE

Serial No.: Not yet assigned Group Art Unit: Not yet assigned
Filed: July 14, 2006 Examiner: Not yet assigned
For: GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR DEVICE AND METHOD FOR MANUFACTURING THE SAME

**INFORMATION DISCLOSURE CITATION
FORM PTO-1449 (Modified)**

U.S. PATENT DOCUMENTS

<u>Exam Init</u>	<u>Ref</u>	<u>Document Number</u>	<u>Issue Date</u>	<u>Name</u>	<u>Class</u>	<u>Sub Class</u>
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FOREIGN PATENT DOCUMENTS

<u>Exam Init</u>	<u>Ref</u>	<u>Document Number</u>	<u>Publication Date</u>	<u>Country</u>	<u>Name</u>
—	—	11-40846	Feb. 12, 99	Japan	Hisanaga Yukihiro, et al.
—	—	2000-36619	Feb. 2, 00	Japan	Kamimura Toshiya
—	—	2000-294837	Oct. 20, 00	Japan	Sato Hiroyuki, et al.
—	—	WO 02/099901 A1	Dec. 12, 02	PCT	Uemura Toshiya

OTHER DOCUMENTS

<u>Exam Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
—	—	English language abstract of Japanese Publication No. 11-40846
—	—	English language abstract of Japanese Publication No. 2000-36619
—	—	English language abstract of Japanese Publication No. 2000-294837

Examiner: _____

Date Considered: _____